NSN 5961-01-172-4180

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Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.635 inches

Overall Width:

0.916 inches

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 drain to source voltage

Current Rating Per Characteristic:

8.00 amperes drain current

Power Rating Per Characteristic:

40.0 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

2 unthreaded hole and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0